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	First Named Inventor	Vincent W. Leung
	Art Unit	2817
	Examiner Name	Nguyen, Khanh V.
Sheet 1 of 1	Attorney Docket Number	0321.72250

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Examiner Initials*	Document No.	Dated	Inventor
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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), city and/or country where published.	T
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